

150V N- Channel Advanced Power MOSFET

MAIN CHARACTERISTICS

I_D	130A
V_{DSS}	150V
R_{DS(on)-typ}(@V_{GS}=10V)	<6.5mΩ(Typ:5.2 mΩ)

Features

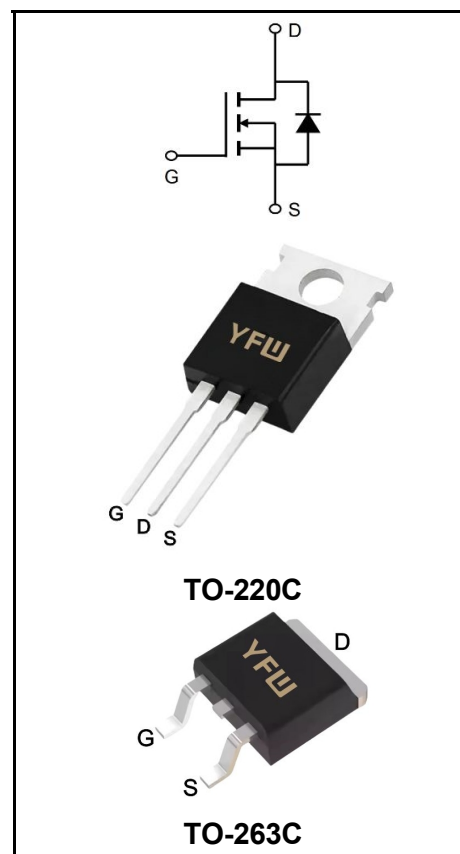
- ◆ **YFW-SGT technology**
- ◆ Pb-free Lead Plating
- ◆ 100% UIS Tested 100%Rg tested
- ◆ Ultra-Low RDS(ON)
- ◆ Low Gate Charge
- ◆ High Current Capability

APPLICATIONS

- ◆ Power Management in Telecom.,Industrial Automation
- ◆ Motor Driving in Power Tool,E-vehicle,Robotics
- ◆ Current Switching in DC/DC&AC/DC(SR) Sub-systems

MECHANICAL DATA

- ◆ Case: Molded plastic
- ◆ Mounting Position: Any
- ◆ Molded Plastic: UL Flammability Classification Rating 94V-0
- ◆ Lead free in compliance with EU RoHS 2011/65/EU directive
- ◆ Solder bath temperature 275℃ maximum,10s per JESD 22-B106



Maximum Ratings at Tc=25℃ unless otherwise specified

Characteristics	Symbols	Value	Units
Drain-Source Voltage	V_{DS}	150	V
Gate - Source Voltage	V_{GS}	±20	V
Continuous drain current	I_D	130	A
Pulsed Drain Current (Note1)	I_{DM}	190	A
Power dissipation	P_D	240	W
Single Pulse Avalanche Energy(Note1)	E_{AS}	864	mJ
Operating Temperature Range	T_J	150	℃
Storage Temperature Range	T_{STG}	-55 to +150	℃
Thermal Resistance, Junction to Case(Note 2)	R_{θJC}	0.52	℃/W
Thermal Resistance, Junction to Ambient	R_{θJA}	45	℃/W

Maximum Ratings at Tc=25°C unless otherwise specified

Characteristics	Test Condition	Symbols	Min	Typ	Max	Units
Drain-Source Breakdown Voltage	$V_{GS}=0V, I_D=250\mu A$	BV_{DSS}	150	-	-	V
Drain-Source Leakage Current	$V_{DS}=150V, V_{GS}=0V$	I_{DSS}	-	-	1	μA
Gate-Source Leakage Current	$V_{GS}=\pm 20V$	I_{GSS}	-	-	± 100	nA
Gate -Threshold Voltage	$V_{DS}=V_{GS}, I_D=250\mu A$	$V_{GS(th)}$	2.5	-	4.5	V
Drain-Source On-State Resistance	$V_{GS}=10V, I_D=20A$	$R_{DS(on)}$	-	5.2	6.5	m Ω
Forward Transconductance	$V_{DS}=5V, I_D=20A$	g_{fs}	-	51	-	S
Input Capacitance	$V_{GS}=0V$ $V_{DS}=75V$ $f=1MHz$	C_{iss}	-	5800	-	pF
Output Capacitance		C_{oss}	-	557	-	
Reverse Transfer Capacitance		C_{rss}	-	16.8	-	
Turn-on delay time	$V_{DS}=75V$ $V_{GS}=10V$ $R_L=3.75\Omega$ $R_{GEN}=3\Omega$	$t_{d(on)}$	-	21	-	ns
Rise Time		T_r	-	39	-	
Turn-Off Delay Time		$t_{d(OFF)}$	-	63	-	
Fall Time		t_f	-	32	-	
Total Gate Charge	$V_{DS}=75V$ $I_D=20A$ $V_{GS}=10V$	Q_g	-	83	-	nC
Gate-Source Charge		Q_{gs}	-	28	-	
Gate-Drain Charge		Q_{gd}	-	19.2	-	
Diode forward current		I_S	-	-	130	A
Diode Forward Voltage	$V_{GS}=0V, I_S=1A, T_J=25^\circ C$	V_{SD}	-	0.7	1.2	V
Reverse Recovery Time	$I_S = I_F, I_{SD}=15A, V_{GS}=0V,$ $di/dt = 100 A/\mu s$	t_{rr}	-	98	-	ns
Reverse Recovery Charge		Q_{rr}	-	316	-	nC

Note2:Pulse test: 300 μs pulse width, 2 % duty cycle

Ratings and Characteristic Curves

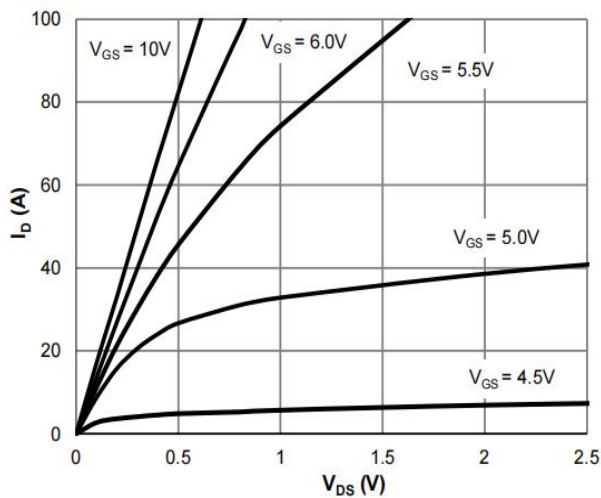


Figure 1: Saturation Characteristics

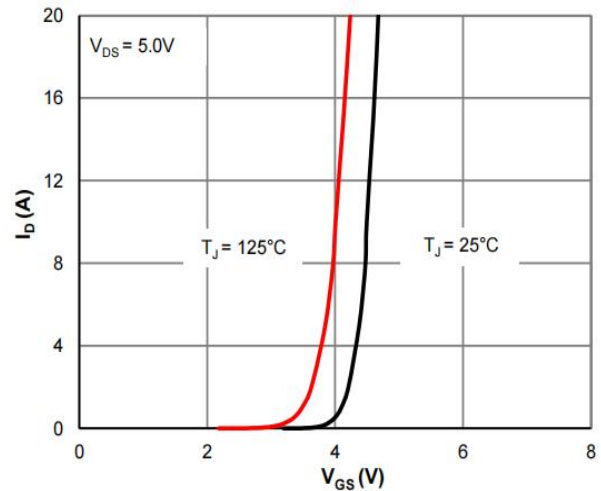


Figure 2: Transfer Characteristics

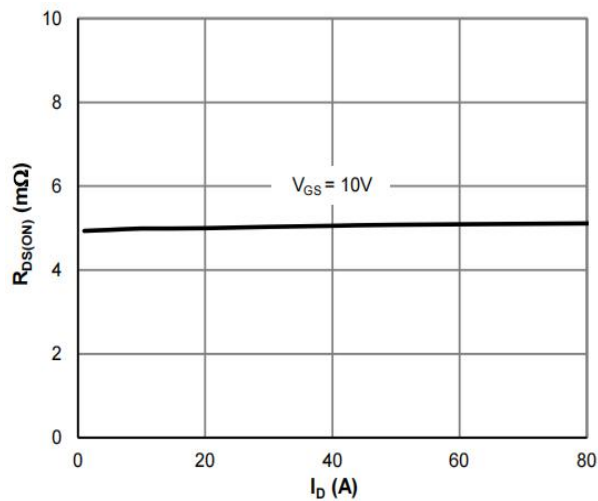


Figure 3: $R_{DS(ON)}$ vs. Drain Current

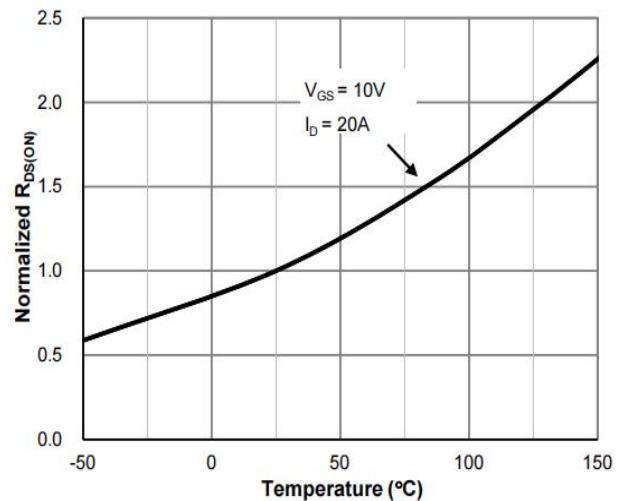


Figure 4: $R_{DS(ON)}$ vs. Junction Temperature

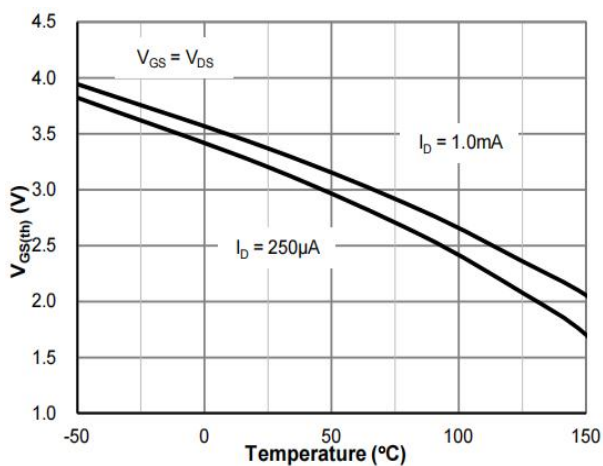


Figure 5: $V_{GS(th)}$ vs. Junction Temperature

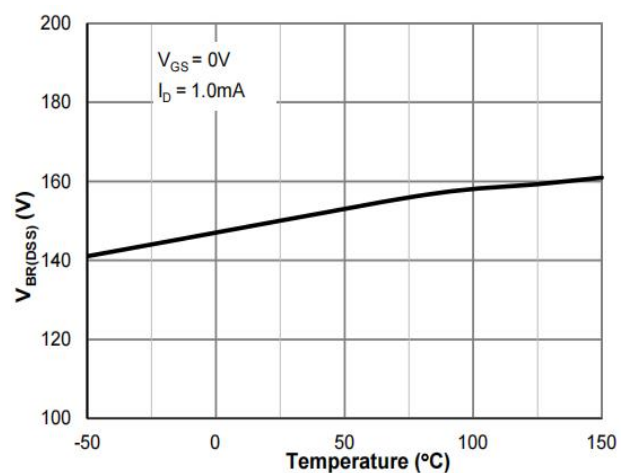


Figure 6: $V_{BR(DSS)}$ vs. Junction Temperature

Ratings and Characteristic Curves

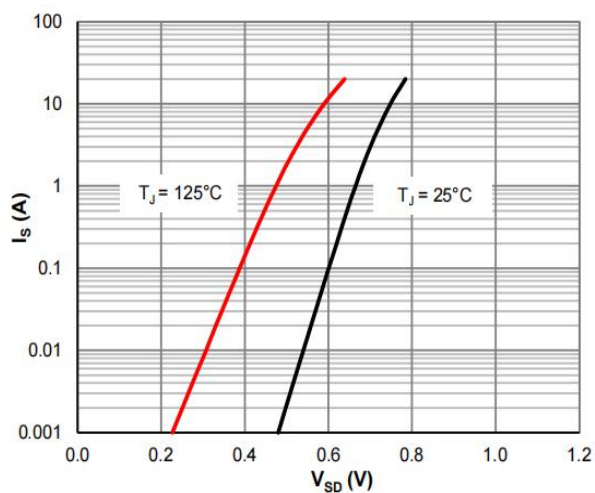


Figure 7: Body-Diode Characteristics

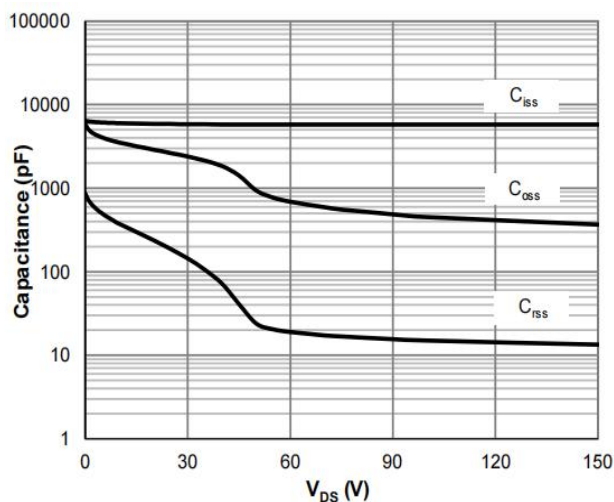


Figure 8: Capacitance Characteristics

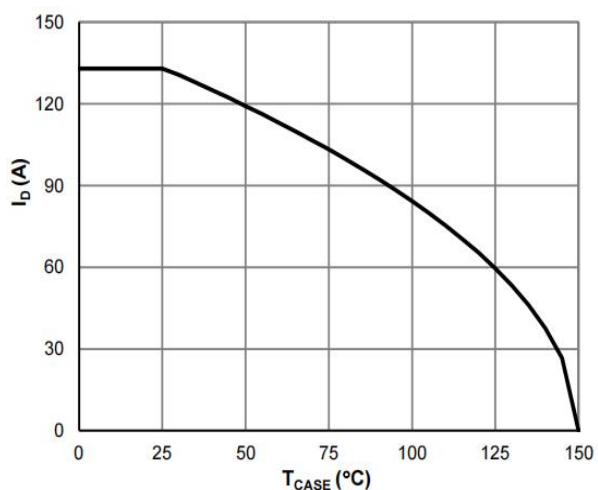


Figure 9: Current De-rating

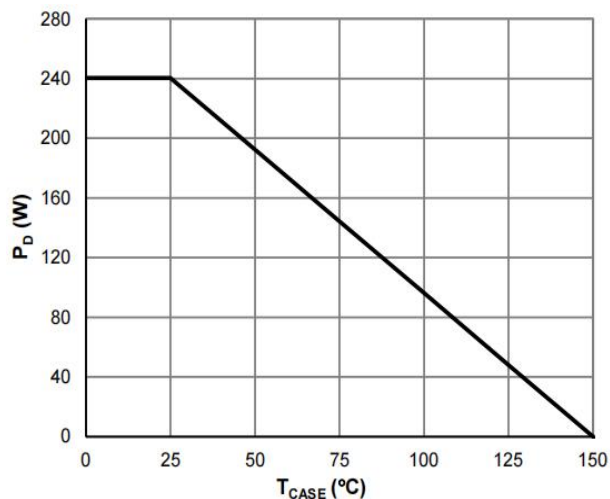


Figure 10: Power De-rating

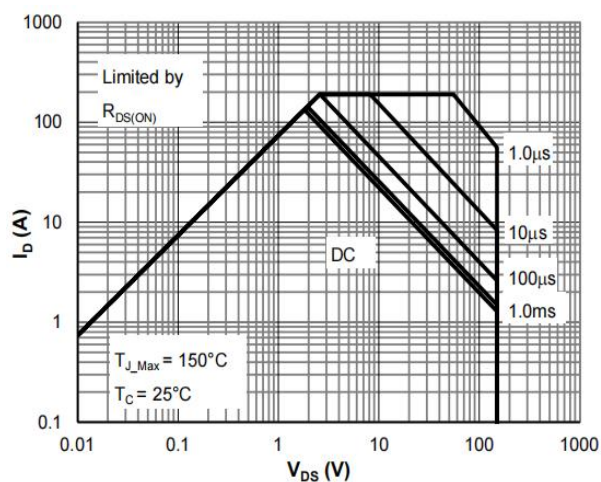


Figure 11: Maximum Safe Operating Area

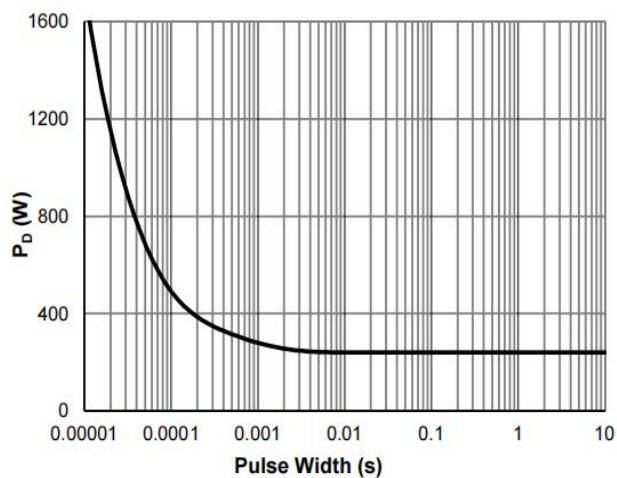
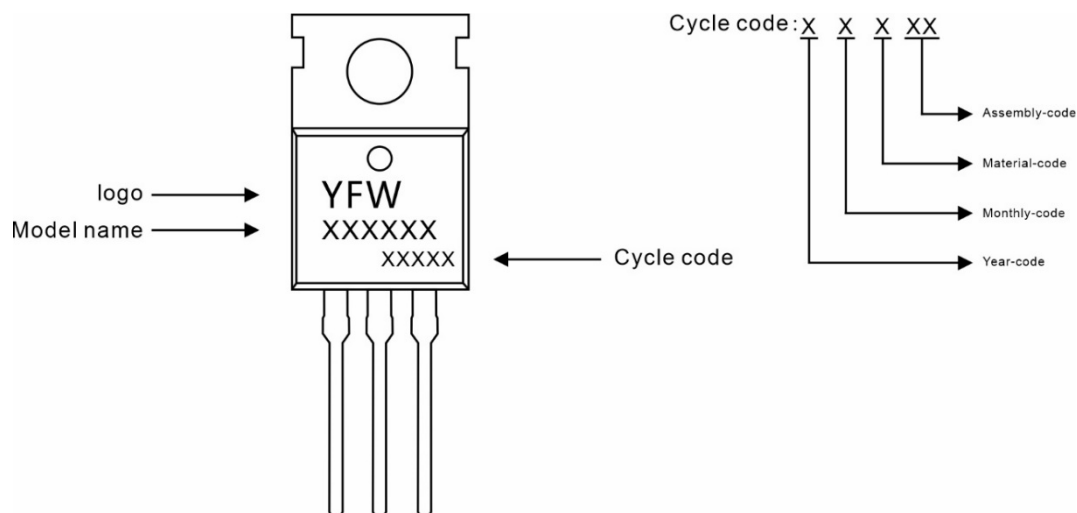


Figure 12: Single Pulse Power Rating, Junction-to-Case

Marking Diagram



Ordering information

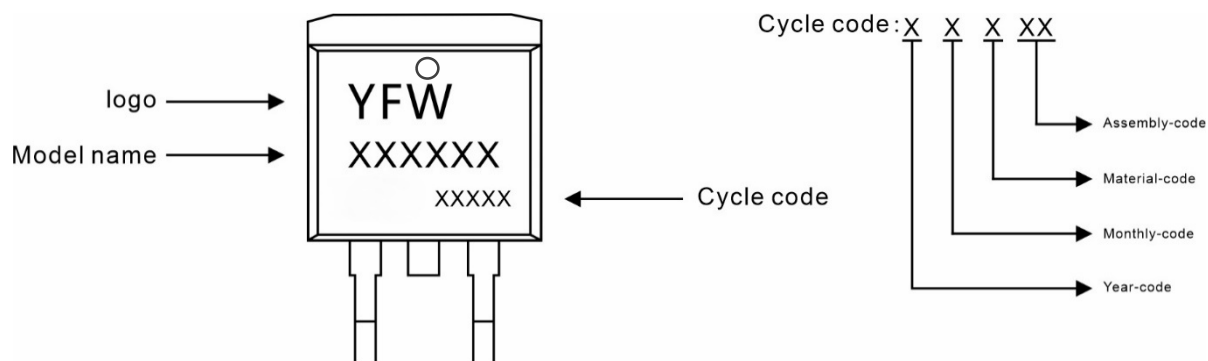
Model name	Package	Unit Weight	Base Quantity	Packing Quantity
YFWG130N15AC	TO-220C	0.07oz(1.96g)	50pcs/tube	1000PCS/Box 5000PCS/Carton

Package Dimensions

TO-220C

Dim	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.34	4.67	0.171	0.184
A1	2.52	2.82	0.099	0.111
b	0.71	0.91	0.028	0.036
b1	1.17	1.37	0.046	0.054
c	0.30	0.50	0.012	0.020
c1	1.17	1.37	0.046	0.054
D	9.90	10.20	0.390	0.402
E	8.50	8.90	0.335	0.350
E1	12.00	12.50	0.472	0.492
e	2.44	2.64	0.096	0.104
e1	4.88	5.28	0.192	0.208
F	2.60	2.80	0.102	0.110
L	13.20	13.80	0.520	0.543
L1	3.80	4.20	0.150	0.165
Φ	3.60	3.96	0.142	0.156

Marking Diagram



Ordering information

Model name	Package	Unit Weight	Base Quantity	Packing Quantity
YFWG130N15ASC	TO-263C	0.04oz(1.16g)	800pcs/reel	1600pcs/box 8000pcs/Carton

Package Dimensions

TO-263C

Dim	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.30	4.70	0.169	0.185
A1	0.00	0.15	0.000	0.006
A2	4.30	4.55	0.169	0.179
B	1.10	1.50	0.043	0.059
b	0.70	0.90	0.028	0.035
b1	1.20	1.50	0.047	0.059
c	0.30	0.60	0.012	0.024
c1	1.17	1.37	0.046	0.054
D	9.90	10.20	0.390	0.402
E	8.50	8.90	0.335	0.350
e	2.44	2.64	0.096	0.104
e1	4.88	5.28	0.192	0.208
L	15.00	15.30	0.591	0.602
L1	5.20	5.40	0.205	0.213
L2	2.40	2.60	0.094	0.102
L3	1.60	1.80	0.063	0.071

Disclaimer

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